TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LVXC3245FS

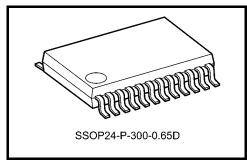
#### Dual Supply Octal Configurable Voltage Interface Bus Transceiver

The TC74LVXC3245FS is a dual supply, advanced high-speed CMOS octal configurable voltage interface bus transceiver fabricated with silicon gate CMOS technology.

Designed for use as an interface between a 3.3 V bus and a 3.3 V to 5 V bus in mixed 3.3 V/5 V supply systems' it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is intended for 2 way asynchronous communication between data busses.

The direction of data transmission is determined by the level of the DIR input. The enable input ( $\overline{G}$ ) can be used to disable the device so that the buses are effectively isolated. The A-port interfaces with



Weight: 0.14 g (typ.)

the 3.3-V bus, the B-port with the 3.3V to 5V bus. This device will allow the  $V_{CCB}$  voltage source pin and I/O pins on the B port to float when  $\overline{G}$  is "H".

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

- Bi-directional interface between 3 V and 5 V buses
- High-speed: t<sub>pd</sub> = 8.5 ns (max)

 $(V_{CCA} = 3.3 \text{ V}, V_{CCB} = 5.0 \text{ V})$ 

- Low power dissipation: I<sub>CC</sub> = 8 μA (max) (Ta = 25°C)
- Symmetrical output impedance: I<sub>OUTA</sub> = ±24 mA (min)

 $I_{OUTB} = \pm 24 \text{ mA (min)}$ 

 $(V_{CCA} = V_{CCB} = 3.0 \text{ V})$ 

- Low noise: V<sub>OLP</sub> = 1.5 V (max)
- Flexible V<sub>CCB</sub> operating range
- Allows B port and  $V_{CCB}$  to float simultaneously when  $\overline{G}$  is "H"
- Package: SSOP (shrink small outline package)

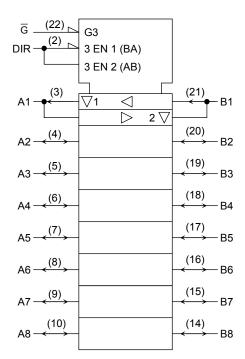
Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pin must have their input levels fixed by means of pull-up or pull-down resistors.

### Pin Assignment (top view)

#### $V_{\text{CCA}}$ 24 $V_{\text{CCB}}$ DIR 2 23 NC $\overline{\mathsf{G}}$ Α1 Α2 В1 А3 5 В2 20 A4 6 19 В3 Α5 18 B4 A6 8 В5 Α7 9 16 В6 В7 A8 10 15 GND 11 B8 GND 12 **GND**

### **IEC Logic Symbol**



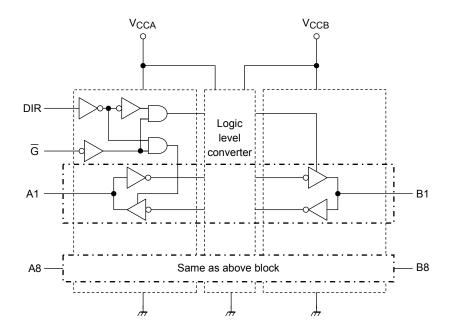
#### **Truth Table**

Inn	uite		Function			
Inputs		Outputs	Full	Clion		
G	DIR	Outputs	A-Bus	B-Bus		
L	L	A = B	Output	Input		
L	Н	B = A	Input	Output		
Н	Х	Z	High impedance			

X: Don't care

Z: High impedance

#### **Block Diagram**



#### **Absolute Maximum Ratings (Note 1)**

Characteristics		Symbol	Rating	Unit
Supply voltage range		$V_{CCA}$	-0.5 to 7.0	V
	(Note 2)	V <sub>CCB</sub>	-0.5 to 7.0	V
DC input voltage	(DIR, $\overline{G}$ )	V <sub>IN</sub>	-0.5 to V <sub>CCA</sub> + 0.5	٧
DC bus I/O voltage		V <sub>I/OA</sub>	-0.5 to V <sub>CCA</sub> + 0.5	>
DC bus I/O voltage		V <sub>I/OB</sub>	-0.5 to V <sub>CCB</sub> + 0.5	V
Input diode current		l <sub>IK</sub>	±20	mA
Output diode current		I <sub>I/OK</sub>	±50	mA
DC output current		I <sub>OUTA</sub>	±50	mA
DC output current		I <sub>OUTB</sub>	±50	Ш
DC Va alground ourrent		I <sub>CCA</sub>	±200	mA
DC V <sub>CC</sub> /ground current		I <sub>CCB</sub>	±200	IIIA
Power dissipation		$P_{D}$	180	mW
Storage temperature		T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

3

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Don't supply a voltage to V<sub>CCB</sub> terminal when V<sub>CCA</sub> is in the OFF state.



### **Operating Ranges (Note 1)**

Characteristics		Symbol	Rating	Unit
Supply voltage range		$V_{CCA}$	2.7 to 3.6	V
	(Note 2)	V <sub>CCB</sub>	3.0 to 5.5	V
Input voltage	(DIR, $\overline{\overline{G}}$ )	$V_{IN}$	0 to V <sub>CCA</sub>	٧
Bus I/O voltage		V <sub>I/OA</sub>	0 to V <sub>CCA</sub>	٧
		V <sub>I/OB</sub>	0 to V <sub>CCB</sub>	V
Operating temperature		T <sub>opr</sub>	-40 to 85	°C
			0 to 8	
Input rise and fall time		dt/dv	$(V_{CCA} = 2.7 \text{ to } 3.6 \text{ V})$	ns/V
input rise and fail time		avav	0 to 8	113/ V
			$(V_{CCB} = 3.0 \text{ to } 5.5 \text{ V})$	

Note1: The operating ranges are required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either  $V_{CC}$  or GND. Please connect both bus inputs and the bus outputs with  $V_{CC}$  or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

4

Note2: Don't use in  $V_{CCA} > V_{CCB}$ .

### **Electrical Characteristics**

#### **DC Characteristics**

Characteri	otioo	Sym-	Test Cond	ition			-	Ta = 25°C			Ta = -40 to 85°C		
Characten	bol		ILION	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Тур.	Max	Min	Max	Unit		
<u></u>					2.7	3.0	2.0	_	_	2.0	_		
	$V_{IHA}$	DIR, $\overline{G}$ , An		3.0	3.6	2.0	_		2.0				
Input voltage					3.6	5.5	2.0	—	_	2.0	_	V	
(V <sub>CCA</sub> )	<del>-</del>				2.7	3.0	_	_	0.8	—	8.0	-	
	L-level	$V_{ILA}$	DIR, $\overline{G}$ , An		3.0	3.6	_	_	0.8	_	8.0		
					3.6	5.5	_	_	0.8	_	0.8		
	le le				2.7	3.0	2.0	_	_	2.0	_		
Input	H-level	$V_{IHB}$	Bn		3.0	3.6	2.0	_	_	2.0	_		
voltage				3.6	5.5	3.85	_	_	3.85	_	V		
(V <sub>CCB</sub> )	le/				2.7	3.0		_	0.8		8.0		
	(VCCB)	$V_{ILB}$	Bn		3.0	3.6			0.8		8.0		
				3.6	5.5			1.65		1.65			
		VOHA		I <sub>OH</sub> = -100 μA	3.0	3.0	2.9	3.0	_	2.9	_		
				I <sub>OH</sub> = -12 mA	3.0	3.0	2.56	_	l	2.46			
	H-level			I <sub>OH</sub> = -24 mA	3.0	3.0	2.35	_		2.25			
Outrout			V <sub>INA</sub> = V <sub>IHA</sub> or	I <sub>OH</sub> = -12 mA	2.7	3.0	2.3	_	_	2.2	_		
Output voltage (V <sub>CCA</sub> )			V <sub>INB</sub> = V <sub>IHB</sub> or	I <sub>OH</sub> = -24 mA	2.7	4.5	2.1	_	_	2.0	_		
(VCCA)			V <sub>ILB</sub>	I <sub>OL</sub> = 100 μA	3.0	3.0	_	0	0.1	_	0.1		
le			I <sub>OL</sub> = 24 mA	3.0	3.0	_	_	0.36	_	0.44			
	L-level	V <sub>OLA</sub>		I <sub>OL</sub> = 12 mA	2.7	3.0	_	_	0.36		0.44		
				I <sub>OL</sub> = 24 mA	2.7	4.5	_	_	0.42	_	0.5		



# **DC Characteristics (continued)**

Characteri	otion	Sym-	Test Condi	ition	•		-	Га = 25°(		Ta = -40 to 85°C		Unit	
Characteristics bol		rest Condi	rest Condition		V <sub>CCB</sub> (V)	Min	Тур.	Max	Min	Max	Offic		
			I <sub>OH</sub> = -100 μA	3.0	3.0	2.9	3.0	_	2.9	_			
	H-level	V <sub>OHB</sub>		I <sub>OH</sub> = -12 mA	3.0	3.0	2.56	_	_	2.46	_		
Output	품	VOHB	V <sub>INA</sub>	I <sub>OH</sub> = -24 mA	3.0	3.0	2.35	_		2.25			
voltage (V <sub>CCB</sub> )			= V <sub>IHA</sub> or V <sub>ILA</sub> V <sub>INB</sub>	I <sub>OH</sub> = -24 mA	3.0	4.5	3.86	_		3.76		V	
(*ССВ)			= V <sub>IHB</sub> or V <sub>ILB</sub>	I <sub>OL</sub> = 100 μA	3.0	3.0	1	0	0.1		0.1		
	L-level	V <sub>OLB</sub>		I <sub>OL</sub> = 24 mA	3.0	3.0		_	0.36	_	0.44		
				I <sub>OL</sub> = 24 mA	3.0	4.5		_	0.36	_	0.44		
		loza	V <sub>INA</sub> = V <sub>IHA</sub> or V <sub>IL</sub>	.A	3.6	3.6		_	±0.5	_	±5.0		
3-state out	out	IOZA	$V_{INB} = V_{IHB}$ or $V_{ILB}$		3.6	5.5			±0.5	_	±5.0	μΑ	
Off-state current		I <sub>OZB</sub>	$VI/OA = V_{CCA}$ or GND $VI/OB = V_{CCB}$ or GND		3.6	3.6		—	±0.5	_	±5.0		
		IOZB			3.6	5.5		—	±0.5	_	±5.0		
Input leaka	ge	I <sub>IN</sub>	V <sub>IN</sub> (DIR, $\overline{G}$ )		3.6	3.6		—	±0.1	_	±1.0	μА	
current		IIN	= V <sub>CCA</sub> or GND		3.6	5.5	_		±0.1	_	±1.0	μΑ	
		Ісст	PER INPUT: V <sub>IN</sub> = 3.0 V		3.6	3.6	_	_	0.35	_	0.5	mA	
Quiescent supply current		I <sub>CCA1</sub>	$An = V_{CCA} \text{ or GND}$ $Bn = Open,$ $\overline{G} = V_{CCA}$ $DIR = V_{CCA},$ $V_{CCB} = Open$		3.6	Open	_	_	5	_	50	μΑ	
		I <sub>CCA2</sub>	V <sub>INA</sub> = V <sub>IHA</sub> or V <sub>IL</sub>	_A	3.6	3.6	_	_	5	_	50	·	
			$V_{INB} = V_{IHB}$ or $V_{IL}$	.В	3.6	5.5	_	_	5	_	50	]	
		loos	V <sub>INA</sub> = V <sub>IHA</sub> or V <sub>IL</sub>	.A	3.6	3.6	_	_	5	_	50		
		I <sub>CCB</sub>	$V_{INB} = V_{IHB}$ or $V_{IL}$	.В	3.6	5.5	_	_	8	_	80		

# AC Characteristics (input: $t_r=t_f=3$ ns, $C_L=50$ pF, $R_L=500~\Omega,\,V_{CCA}\text{=}2.7$ to 3.6 V)

Characteristics	Symbol Test Condition			Ta	a = 25°C		Ta = -4 85°	Unit	
Characteristics	Cymbol		V <sub>CCB</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub>		5.0 ± 0.5	_	5.7	8.0	1.0	8.5	ns
$(An \rightarrow Bn)$	t <sub>pHL</sub>	Input: An	3.3 ± 0.3	_	6.2	8.5	1.0	9.0	115
3-state output enable time	t <sub>pZL</sub>	Output: Bn	5.0 ± 0.5	_	6.5	9.5	1.0	10.0	ns
$(\overline{G} \to Bn)$	t <sub>pZH</sub>	(DIR = "H")	3.3 ± 0.3	_	7.4	10.5	1.0	11.5	115
3-state output disable time	t <sub>pLZ</sub>		5.0 ± 0.5	I	7.3	9.5	1.0	10.0	ne
$(\overline{G} \to Bn)$	t <sub>pHZ</sub>		3.3 ± 0.3	_	6.6	9.5	1.0	10.0	ns
Propagation delay time	t <sub>pLH</sub>		5.0 ± 0.5	I	4.6	7.5	1.0	8.0	ns
$(Bn \rightarrow An)$	t <sub>pHL</sub>	Input: Bn	$3.3\pm0.3$	I	5.2	7.5	1.0	8.0	113
3-state output enable time	t <sub>pZL</sub>	Output: An	5.0 ± 0.5	_	7.0	10.5	1.0	11.5	ns
$(\overline{G} \to An)$	t <sub>pZH</sub>	(DIR = "L")	3.3 ± 0.3	_	7.0	10.5	1.0	11.5	115
3-state output disable time	t <sub>pLZ</sub>	(DIIV = L)	5.0 ± 0.5	_	6.1	9.5	1.0	10.0	ns
$(\overline{G} \to An)$	t <sub>pHZ</sub>		3.3 ± 0.3	_	6.0	9.5	1.0	10.0	115
Output to output skew	t <sub>osLH</sub>	(Note 1)	5.0 ± 0.5	_	_	1.5	_	1.5	ne
Output to output skew	t <sub>osHL</sub>	(Note 1)	3.3 ± 0.3	_	_	1.5	_	1.5	ns
Input capacitance	C <sub>INA</sub>	DIR, G	5.0 ± 0.5		5	10	_	10	pF
Bus input capacitance	C <sub>I/O</sub>	An, Bn	3.0 ± 0.3	I	8	_	_		ρι
	Con	A → B (DIR = "H")	5.0 ± 0.5	_	4	_	_	_	
Power dissipation capacitance	C <sub>PDA</sub>	B → A (DIR = "L")	3.0 ± 0.5		38	_	_	_	pF
(Note 2)	C <sub>PDB</sub>	A → B (DIR = "H")	5.0 ± 0.5	_	88	_	_	_	ρι
, ,	CADR	$B \rightarrow A(DIR = "L")$	5.0 ± 0.5	_	7	_	_		

Note 1: Parameter guaranteed by design.  $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, \, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$ 

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

7

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per bit)}$ 

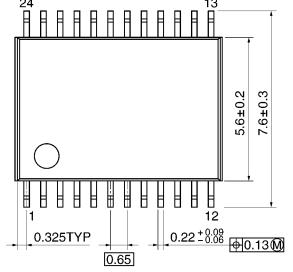
## Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF, $R_L = 500~\Omega$ )

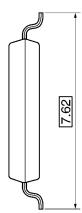
21						_			
Characteristics		Symbol	Test Condition	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Тур.	Limit	Unit	
Quiet output maximum	V <sub>OL</sub> (A)	Vo. a. Janut Da		3.3	3.3	_	0.9		
dynamic	VOL (A)	V <sub>OLPA</sub>	Input: Bn Output: An	3.3	5.0	_	0.9		
Quiet output mimimum		(DIR = "L")	3.3	3.3	_	-0.9			
dynamic	V <sub>OL</sub> (A)	V <sub>OLVA</sub>	(DIK = L)	3.3	5.0	_	-0.9		
Quiet output maximum	V <sub>OL</sub> (B)	.,		3.3	3.3	_	0.8	V	
dynamic		V <sub>OLPB</sub>	Input: An Output: Bn (DIR = "H")	3.3	5.0	_	1.5	-	
Quiet output mimimum dynamic	V <sub>OL</sub> (B)			3.3	3.3	_	-0.8		
		V <sub>OLVB</sub>		3.3	5.0	_	-1.2		
Minimum high level dynamic	\/ (A)	V	Input: An	3.3	3.3	_	2.0	V	
input voltage	V <sub>IH</sub> (A)	V <sub>IHDA</sub>		3.3	5.0	_	2.0	]	
Maximum low level dynamic	V <sub>IL</sub> (A)	\/ (A)	\/	Innut: An	3.3	3.3	_	0.8	V
input Voltage		$V_{ILDA}$	Input: An	3.3	5.0	_	0.8	V	
Minimum high level dynamic	\/(P\	Vuine	Input: Bn	3.3	3.3	2.0	_	V	
input voltage	V <sub>IH</sub> (B)	V <sub>IHDB</sub>	iliput. Dii	3.3	5.0	3.5	_	V	
Maximum low level dynamic	V., (B)	V <sub>ILDB</sub>	Input: Bn	3.3	3.3	0.8	_	V	
input voltage	V <sub>IL</sub> (B)		IIIput. DII	3.3	5.0	1.5	_	V	

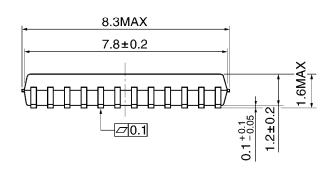
### **Package Dimensions**

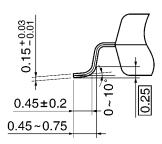
SSOP24-P-300-0.65D

Unit: mm









Weight: 0.14 g (typ.)

#### RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
  EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
  MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
  ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
  limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
  automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions,
  safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
  PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
  TOSHIBA sales representative.
- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
  FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
  WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
  LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
  LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
  SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
  FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
  limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
  technology products (mass destruction weapons). Product and related software and technology may be controlled under the
  applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
  U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
  except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
   Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
   OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.